

MICRO ELECTRONICS

MG136A/C
MY136A/C
MO136A/C

0.36" SINGLE DIGIT
NUMERIC DISPLAYS

SEVEN SEGMENT NUMERIC DISPLAY

High Performance GaP, GaAsP Dice
0.36 inch Character Height
High Contrast
Wide Viewing Angle
Common Anode - MS136A, MG136A, MY136A, MO136A
Common Cathode - MS136C, MG136C, MY136C, MO136C

ABSOLUTE MAXIMUM RATINGS

	MG136			UNIT
	MS136	MY136	MO136	
Power Dissipation / Segment	40	60	75	mW
Peak Forward Current / Segment*	60	80	100	mA
Continuous Forward Current / Segment	15	20	25	mA
Reverse Voltage / Segment	5	5	5	V
Operating Temperature Range	-25 to +85			°C
Storage Temperature Range	-25 to +85			°C

* Note : Pulse Width = 1mS, Duty Ratio = 1/10.

ELECTRO-OPTICAL CHARACTERISTICS (Ta=25°C)

PARAMETER	SYMBOL	MS136	MG136	MY136	MO136	UNIT	CONDITIONS
Forward Voltage	MAX VF	3.0	3.0	3.0	3.0	V	IF=20mA
Luminous Intensity	MIN IV	330	1200	800	1000	μcd	IF=10mA
Segment to Segment	MAX	2:1	2:1	2:1	2:1		IF=20mA
Luminous Intensity Ratio							
Peak Wavelength	TYP λp	700	565	585	630	nm	IF=20mA
Spectral Line Half Width	TYP Δλ	100	30	35	40	nm	IF=20mA

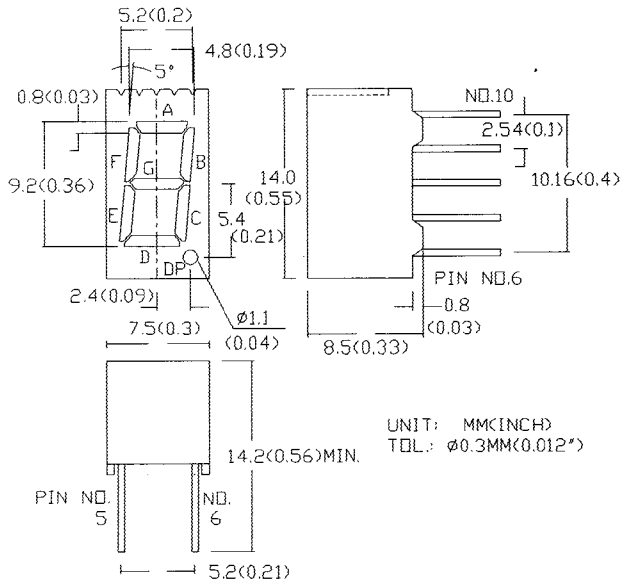


MICRO ELECTRONICS LTD.

38, Hung To Road, Microtron Building, Kwun Tong, Kowloon, Hong Kong.
Kwun Tong P.O. Box 69477 Hong Kong. Fax No. 2341 0321 Telex:43510 Micro Hx. Tel: 2343 0181-5

Dec-96

MECHANICAL OUTLINE.



CIRCUIT DIAGRAM:

